

## PNP power transistor

#### **Features**

■ PNP transistor

#### **Applications**

■ Linear and switching industrial equipment

### **Description**

This devices is manufactured in Planar technology with "Base Island" layout. The resulting transistor shows exceptional high gain performance coupled with very low saturation voltage. The NPN type is BD441.

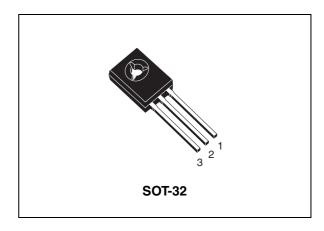


Figure 1. Internal schematic diagram

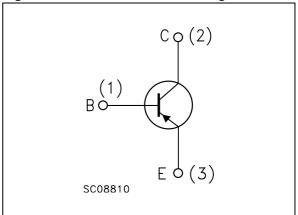


Table 1. Device summary

Order code	Marking	Package	Packaging
BD442	BD442	SOT-32	Tube

# 1 Absolute maximum ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V <sub>CBO</sub>	Collector-base voltage (I <sub>E</sub> = 0)	-80	V
V <sub>CES</sub>	Collector-emitter voltage (V <sub>BE</sub> = 0)	-80	V
V <sub>CEO</sub>	Collector-emitter voltage (I <sub>B</sub> = 0)	-80	V
V <sub>EBO</sub>	Emitter-base voltage ( $I_C = 0$ )	-5	V
I <sub>C</sub>	Collector current	-4	Α
I <sub>CM</sub>	Collector peak current (t <sub>p</sub> < 10 ms)	-7	Α
I <sub>B</sub>	Base current	-1	Α
P <sub>TOT</sub>	Total dissipation at T <sub>case</sub> = 25 °C	36	W
T <sub>stg</sub>	Storage temperature	-65 to 150	°C
T <sub>J</sub>	Max. operating junction temperature	150	°C

## 2 Electrical characteristics

 $(T_{case} = 25 \, ^{\circ}C; \text{ unless otherwise specified})$ 

Table 3. Electrical characteristics

Symbol	Parameter	Test cor	nditions	Min.	Тур.	Max.	Unit
I <sub>CBO</sub>	Collector cut-off current (I <sub>E</sub> = 0)	V <sub>CB</sub> = -80 V				-0.1	mA
I <sub>CES</sub>	Collector cut-off current (V <sub>BE</sub> = 0)	V <sub>CE</sub> = -80 V				-0.1	mA
I <sub>EBO</sub>	Emitter cut-off current (I <sub>C</sub> = 0)	V <sub>EB</sub> = -5 V				-1	mA
V <sub>CEO(sus)</sub> <sup>(1)</sup>	Collector-emitter sustaining voltage (I <sub>B</sub> = 0)	I <sub>C</sub> = -100 mA		-80			V
V <sub>CE(sat)</sub> <sup>(1)</sup>	Collector-emitter saturation voltage	I <sub>C</sub> = -2 A	I <sub>B</sub> = -0.2 A			-0.8	V
V <sub>BE</sub> <sup>(1)</sup>	Base-emitter voltage	$I_{C} = -10 \text{ mA}$ $I_{C} = -2 \text{ A}$	~ —		-0.58	-1.5	V V
h <sub>FE</sub> <sup>(1)</sup>	DC current gain	$I_C = -10 \text{ mA}$ $I_C = -500 \text{ mA}$ $I_C = -2 \text{ A}$	$V_{CE} = -1 V$	15 40 15	130 140		

<sup>1.</sup> Pulsed duration = 300 ms, duty cycle  $\geq$  1.5%.

Electrical characteristics BD442

## 2.1 Electrical characteristics (curves)

Figure 2. DC current gain

Figure 3. DC current gain

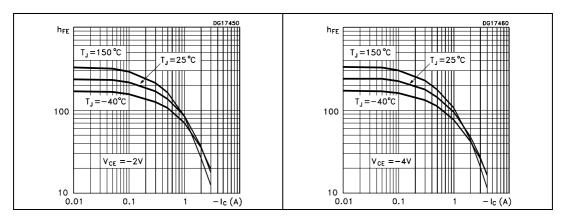


Figure 4. Collector-emitter saturation voltage

Figure 5. Base-emitter saturation voltage

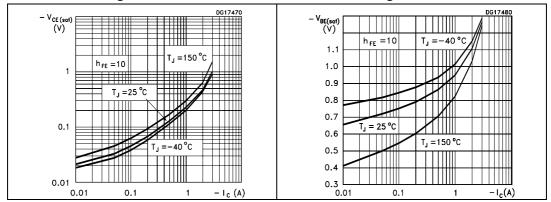
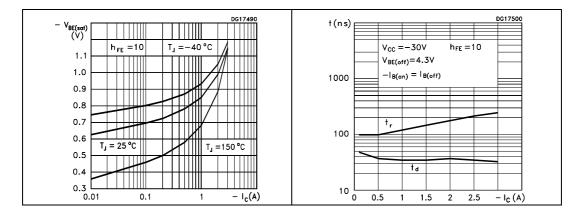


Figure 6. Collector-emitter on voltage

Figure 7. Resistive load switching time



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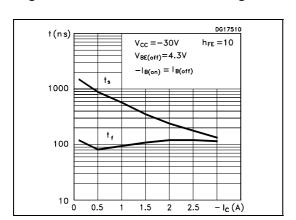
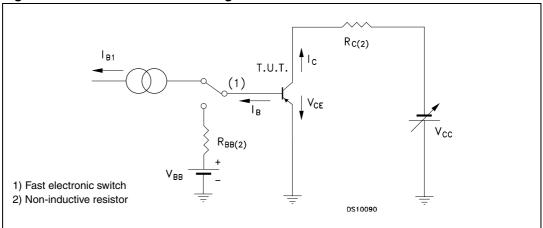


Figure 8. Resistive load switching time

### 2.2 Test circuit

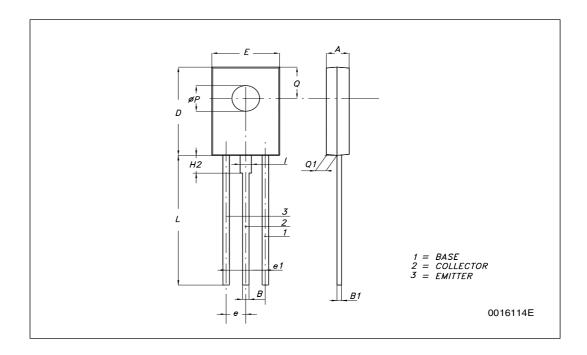
Figure 9. Resistive load switching test circuit



# 3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: <a href="https://www.st.com">www.st.com</a>

DIM.	mm.		
	MIN.	TYP	MAX.
Α	2.4		2.9
В	0.64		0.88
B1	0.39		0.63
D	10.5		11.05
E	7.4		7.8
е	2.04	2.29	2.54
e1	4.07	4.58	5.08
L	15.3		16
Р	2.9		3.2
Q		3.8	
Q1	1		1.52
H2		2.15	
I		1.27	



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Revision history BD442

# 4 Revision history

Table 4. Document revision history

Date	Revision	Changes
08-Feb-2008	1	Initial Release
09-Jun-2008	2	Removed BD440

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